

General Description

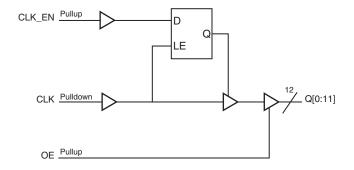
The 8312I is a low skew, 1-to-12 LVCMOS/ LVTTL Fanout Buffer and a member of the family of High Performance Clock Solutions from IDT. The 8312I single-ended clock input accepts LVCMOS or LVTTL input levels. The low impedance LVCMOS outputs are designed to drive 50Ω series or parallel terminated transmission lines. The effective fanout can be increased from 12 to 24 by utilizing the ability of the outputs to drive two series terminated lines.

The 8312I is characterized at full 3.3V, 2.5V, and 1.8V, mixed 3.3V/2.5V, 3.3V/1.8V and 2.5V/1.8V output operating supply modes. Guaranteed output and part-to-part skew characteristics along with the 1.8V output capabilities makes the 8312I ideal for high performance, single ended applications that also require a limited output voltage.

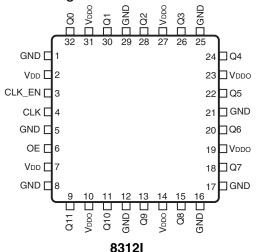
Features

- Twelve LVCMOS/LVTTL outputs
- · CLK input supports the following input types: LVCMOS, LVTTL
- Maximum output frequency: 250MHz
- Output skew: 160ps (maximum)
- Supply modes: Core/Output
 - 3.3V/3.3V
 - 3.3V/2.5V
 - 3.3V/1.8V
 - 2.5V/2.5V 2.5V/1.8V
 - 1.8V/1.8V
- -40°C to 85°C ambient operating temperature
- · Available in lead-free (RoHS 6) package

Block Diagram



Pin Assignment



32-Lead LQFP 7mm x 7mm x 1.4mm package body Y Package Top View



Table 1. Pin Descriptions

Number	Name	T	уре	Description
1, 5, 8, 12, 16, 17, 21, 25, 29	GND	Power		Power supply ground.
2, 7	V_{DD}	Power		Positive supply pins.
3	CLK_EN	Input	Pullup	Synchronous control for enabling and disabling clock outputs. LVCMOS / LVTTL interface levels.
4	CLK	Input	Pulldown	Single-ended clock input. LVCMOS/LVTTL interface levels.
6	OE	Input	Pullup	Output enable. Controls enabling and disabling of outputs Q[0:11]. LVCMOS / LVTTL interface levels.
9, 11, 13, 15, 18, 20, 22, 24, 26, 28, 30, 32	Q11, Q10, Q9, Q8, Q7, Q6, Q5, Q4, Q3, Q2, Q1, Q0	Output		Single-ended clock outputs. LVCMOS/LVTTL interface levels.
10, 14, 19, 23, 27, 31	V _{DDO}	Power		Output supply pins.

NOTE: Pullup and Pulldown refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C _{IN}	Input Capacitance			4		pF
R _{PULLUP}	Input Pullup Resistor			51		kΩ
R _{PULLDOWN}	Input Pulldown Resistor			51		kΩ
		V _{DDO} = 3.465V			19	pF
C _{PD}	Power Dissipation Capacitance (per output); NOTE 1	V _{DDO} = 2.625V			18	pF
		V _{DDO} = 2.V			16	pF
		$V_{DDO} = 3.3V \pm 5\%$		7		Ω
R _{OUT}	Output Impedance	V _{DDO} = 2.5V ± 5%		7		Ω
		$V_{DDO} = 1.8V \pm 0.2V$		10		Ω



Function Tables

Table 3A. Output Enable and Clock Enable Function Table

Inp	uts	Outputs		
OE CLK_EN		Q [0:11]		
0	Х	Hi-Z		
1	0	LOW		
1	1	Follows CLK input		

Table 3B. Output Enable and Clock Enable Function Table

	Outputs		
OE	CLK	Q [0:11]	
1	1	0	LOW
1	1	1	HIGH



Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V _{DD}	4.6V
Inputs, V _I	-0.5V to V _{DD} + 0.5V
Outputs, V _O	-0.5V to V _{DDO} + 0.5V
Package Thermal Impedance, θ_{JA}	47.9°C/W (0 Ifpm)
Storage Temperature, T _{STG}	-65°C to 150°C

DC Electrical Characteristics

Table 4A. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = -40$ °C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		3.135	3.3	3.465	V
I _{DD}	Power Supply Current				10	mA
I_{DDO}	Output Supply Current				10	mA

Table 4B. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 2.5V \pm 5\%$, $T_A = -40^{\circ}C$ to $85^{\circ}C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		2.375	2.5	2.625	٧
V_{DDO}	Output Supply Voltage		2.375	2.5	2.625	٧
I _{DD}	Power Supply Current				10	mA
I _{DDO}	Output Supply Current				10	mA

Table 4C. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 1.8V \pm 0.2V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V _{DD}	Positive Supply Voltage		1.6	1.8	2.0	V
V_{DDO}	Output Supply Voltage		1.6	1.8	2.0	V
I _{DD}	Power Supply Current				10	mA
I _{DDO}	Output Supply Current				10	mA



Table 4D. Power Supply DC Characteristics, V_{DD} = 3.3V \pm 5%, V_{DDO} = 2.5V \pm 5%, T_A = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		2.375	2.5	2.625	V
I _{DD}	Power Supply Current				10	mA
I _{DDO}	Output Supply Current				10	mA

Table 4E. Power Supply DC Characteristics, V_{DD} = 3.3V \pm 5%, V_{DDO} = 1.8V \pm 0.2V, T_A = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		1.6	1.8	2.0	V
I _{DD}	Power Supply Current				10	mA
I _{DDO}	Output Supply Current				10	mA

Table 4F. Power Supply DC Characteristics, V_{DD} = 2.5V \pm 5%, V_{DDO} = 1.8V \pm 0.2V, T_A = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		2.375	2.5	2.625	V
V_{DDO}	Output Supply Voltage		1.6	1.8	2.0	V
I _{DD}	Power Supply Current				10	mA
I _{DDO}	Output Supply Current				10	mA



Table 4G. LVCMOS/LVTTL DC Characteristics, $T_A = -40\,^{\circ}\text{C}$ to $85\,^{\circ}\text{C}$

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
			V _{DD} = 3.465V	2		V _{DD} + 0.3	V
V_{IH}	Input High Volta	age	V _{DD} = 2.625V	1.7		V _{DD} + 0.3	V
			V _{DD} = 2.0V	0.65*V _{DD}		V _{DD} + 0.3	V
			V _{DD} = 3.465V	-0.3		1.3	٧
V_{IL}	Input Low Volta	age	V _{DD} = 2.625V	-0.3		0.7	٧
			V _{DD} = 2.0V	-0.3		0.35*V _{DD}	V
I _{IH}	Input	CLK	V _{DD} = V _{IN} = 3.465V or 2.625V or 2.0V			150	μΑ
	High Current	OE, CLK_EN	V _{DD} = V _{IN} = 3.465V or 2.625V or 2.0V			5	μΑ
	Input Low Current	CLK	$V_{DD} = 3.465V \text{ or } 2.625V \text{ or } 2.0V,$ $V_{IN} = 0V$	-5			μΑ
I _{IL}		OE, CLK_EN	$V_{DD} = 3.465V \text{ or } 2.625V \text{ or } 2.0V,$ $V_{IN} = 0V$	-150			μΑ
			$V_{DDO} = 3.3V \pm 5\%$	2.6			٧
			$V_{DDO} = 2.5V \pm 5\%;$	1.8			V
V_{OH}	Output High Vo	oltage; NOTE 1	$V_{DDO} = 2.5V \pm 5\%; I_{OH} = -1mA$	2			٧
			$V_{DDO} = 1.8V \pm 0.2V$	V _{DD} - 0.3			V
			$V_{DDO} = 1.8V \pm 0.2V; I_{OH} = -100\mu A$	V _{DD} - 0.2			٧
			$V_{DDO} = 3.3V \pm 5\%$			0.5	٧
V _{OL}			$V_{DDO} = 2.5V \pm 5\%;$			0.45	V
	Output Low Vo	ltage; NOTE 1	$V_{DDO} = 2.5V \pm 5\%; I_{OL} = 1mA$			0.4	٧
			$V_{DDO} = 1.8V \pm 0.2V$			0.35	V
			$V_{DDO} = 1.8V \pm 0.2V; I_{OL} = 100\mu A$			0.2	V

NOTE 1: Outputs terminated with 50Ω to $V_{DDO}/2$. See Parameter Measurement Information, *Output Load Test Circuit diagrams*.



AC Electrical Characteristics

Table 5A. AC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = -40$ °C to 85°C

Parameter	Symbol	Test Conditions	Minimum	Typical	Maximum	Units
f _{MAX}	Output Frequency				250	MHz
tp _{LH}	Propagation Delay, Low to High; NOTE 1	<i>f</i> ≤ 250MHz	1.2	2.0	2.7	ns
tjit	Buffer Additive Phase Jitter, RMS; refer to Additive Phase Jitter Section	100MHz, Integration Range: 12kHz – 20MHz		0.037		ps
tsk(o)	Output Skew; NOTE 2, 5				150	ps
tsk(pp)	Part-to-Part Skew; NOTE 3, 5				850	ps
t _R / t _F	Output Rise/Fall Time; NOTE 5	20% to 80%	175		800	ps
odc	Output Duty Cycle	<i>f</i> ≤ 150MHz	45		55	%

All parameters measured at f_{MAX} unless noted otherwise.

NOTE 1: Measured from the $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at V_{DDO}/2.

NOTE 3: Defined as skew between outputs on different devices operating a the same supply voltage and with equal load conditions.

Using the same type of input on each device, the output is measured at V_{DDO}/2.

NOTE 4: These parameters are guaranteed by characterization. Not tested in production.

NOTE 5: This parameter is defined in accordance with JEDEC Standard 65.

Table 5B. AC Characteristics, $V_{DD} = V_{DDO} = 2.5V \pm 5\%$, $T_A = -40$ °C to 85°C

Parameter	Symbol	Test Conditions	Minimum	Typical	Maximum	Units
f _{MAX}	Output Frequency				250	MHz
tp _{LH}	Propagation Delay, Low to High; NOTE 1	<i>f</i> ≤ 250MHz	1.25	2.4	3.5	ns
tjit	Buffer Additive Phase Jitter, RMS; refer to Additive Phase Jitter Section	100MHz, Integration Range: 12kHz – 20MHz		0.022		ps
tsk(o)	Output Skew; NOTE 2, 5				155	ps
tsk(pp)	Part-to-Part Skew; NOTE 3, 5				1.1	ns
t _R / t _F	Output Rise/Fall Time; NOTE 5	20% to 80%	200		800	ps
odc	Output Duty Cycle	<i>f</i> ≤ 150MHz	45		55	%

All parameters measured at f_{MAX} unless noted otherwise.

NOTE 1: Measured from the $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at V_{DDO}/2.

NOTE 3: Defined as skew between outputs on different devices operating a the same supply voltage and with equal load conditions.

Using the same type of input on each device, the output is measured at $V_{DDO}/2$.

NOTE 4: These parameters are guaranteed by characterization. Not tested in production.

NOTE 5: This parameter is defined in accordance with JEDEC Standard 65.



Table 5C. AC Characteristics, $V_{DD} = V_{DDO} = 1.8V \pm 0.2V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$

Parameter	Symbol	Test Conditions	Minimum	Typical	Maximum	Units
f _{MAX}	Output Frequency				200	MHz
tp _{LH}	Propagation Delay, Low to High; NOTE 1	<i>f</i> ≤ 200MHz	1.6	3.3	4.9	ns
tjit	Buffer Additive Phase Jitter, RMS; refer to Additive Phase Jitter Section	100MHz, Integration Range: 12kHz – 20MHz		0.172		ps
tsk(o)	Output Skew; NOTE 2, 5				160	ps
tsk(pp)	Part-to-Part Skew; NOTE 3, 5				2.4	ns
t _R / t _F	Output Rise/Fall Time; NOTE 5	20% to 80%	175		875	ps
odc	Output Duty Cycle	<i>f</i> ≤ 100MHz	45		55	%

All parameters measured at f_{MAX} unless noted otherwise.

NOTE 1: Measured from the $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at V_{DDO}/2.

NOTE 3: Defined as skew between outputs on different devices operating a the same supply voltage and with equal load conditions.

Using the same type of input on each device, the output is measured at V_{DDO}/2.

NOTE 4: These parameters are guaranteed by characterization. Not tested in production.

NOTE 5: This parameter is defined in accordance with JEDEC Standard 65.

Table 5D. AC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, $T_A = -40$ °C to 85°C

Parameter	Symbol	Test Conditions	Minimum	Typical	Maximum	Units
f _{MAX}	Output Frequency				250	MHz
tp _{LH}	Propagation Delay, Low to High; NOTE 1	<i>f</i> ≤ 250MHz	1.5	2.1	2.8	ns
tjit	Buffer Additive Phase Jitter, RMS; refer to Additive Phase Jitter Section	100MHz, Integration Range: 12kHz – 20MHz		0.045		ps
tsk(o)	Output Skew; NOTE 2, 5				150	ps
tsk(pp)	Part-to-Part Skew; NOTE 3, 5				1	ns
t _R / t _F	Output Rise/Fall Time; NOTE 5	20% to 80%	200		800	ps
odc	Output Duty Cycle	<i>f</i> ≤ 150MHz	45		55	%

All parameters measured at $f_{\mbox{\scriptsize MAX}}$ unless noted otherwise.

NOTE 1: Measured from the $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at V_{DDO}/2.

NOTE 3: Defined as skew between outputs on different devices operating a the same supply voltage and with equal load conditions.

Using the same type of input on each device, the output is measured at V_{DDO}/2.

NOTE 4: These parameters are guaranteed by characterization. Not tested in production.

NOTE 5: This parameter is defined in accordance with JEDEC Standard 65.



Table 5E. AC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 1.8V \pm 0.2V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$

Parameter	Symbol	Test Conditions	Minimum	Typical	Maximum	Units
f _{MAX}	Output Frequency				200	MHz
tp _{LH}	Propagation Delay, Low to High; NOTE 1	<i>f</i> ≤ 200MHz	1.5	2.5	3.5	ns
tjit	Buffer Additive Phase Jitter, RMS; refer to Additive Phase Jitter Section	100MHz, Integration Range: 12kHz – 20MHz		0.136		ps
tsk(o)	Output Skew; NOTE 2, 5				150	ps
<i>t</i> sk(pp)	Part-to-Part Skew; NOTE 3, 5				1.4	ns
t _R / t _F	Output Rise/Fall Time; NOTE 5	20% to 80%	200		800	ps
odc	Output Duty Cycle	<i>f</i> ≤ 100MHz	45		55	%

All parameters measured at $f_{\mbox{\scriptsize MAX}}$ unless noted otherwise.

NOTE 1: Measured from the $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at V_{DDO}/2.

NOTE 3: Defined as skew between outputs on different devices operating a the same supply voltage and with equal load conditions.

Using the same type of input on each device, the output is measured at V_{DDO}/2.

NOTE 4: These parameters are guaranteed by characterization. Not tested in production.

NOTE 5: This parameter is defined in accordance with JEDEC Standard 65.

Table 5F. AC Characteristics, $V_{DD} = 2.5V \pm 5\%$, $V_{DDO} = 1.8V \pm 0.2V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$

Parameter	Symbol	Test Conditions	Minimum	Typical	Maximum	Units
f _{MAX}	Output Frequency				200	MHz
tp _{LH}	Propagation Delay, Low to High; NOTE 1	<i>f</i> ≤ 200MHz	1.4	2.7	3.9	ns
tjit	Buffer Additive Phase Jitter, RMS; refer to Additive Phase Jitter Section	100MHz, Integration Range: 12kHz – 20MHz		0.114		ps
tsk(o)	Output Skew; NOTE 2, 5				160	ps
tsk(pp)	Part-to-Part Skew; NOTE 3, 5				1.6	ns
t _R / t _F	Output Rise/Fall Time; NOTE 5	20% to 80%	200		800	ps
odc	Output Duty Cycle	<i>f</i> ≤ 100MHz	45		55	%

All parameters measured at f_{MAX} unless noted otherwise.

NOTE 1: Measured from the $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at V_{DDO}/2.

NOTE 3: Defined as skew between outputs on different devices operating a the same supply voltage and with equal load conditions.

Using the same type of input on each device, the output is measured at $V_{DDO}/2$.

NOTE 4: These parameters are guaranteed by characterization. Not tested in production.

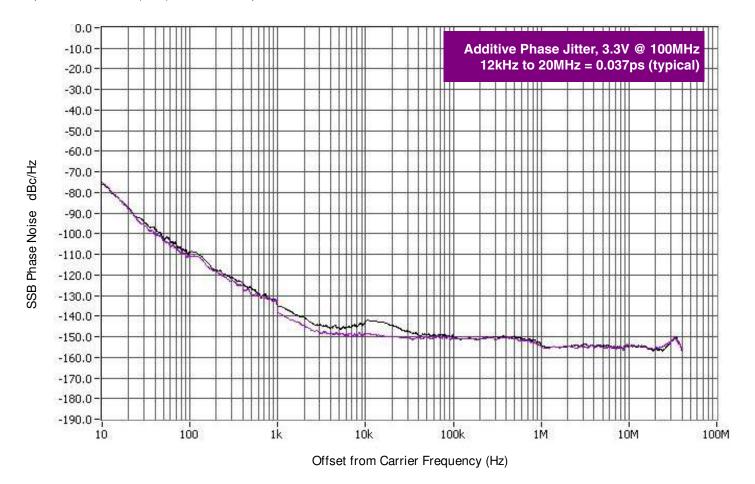
NOTE 5: This parameter is defined in accordance with JEDEC Standard 65.



Additive Phase Jitter

The spectral purity in a band at a specific offset from the fundamental compared to the power of the fundamental is called the *dBc Phase Noise*. This value is normally expressed using a Phase noise plot and is most often the specified plot in many applications. Phase noise is defined as the ratio of the noise power present in a 1Hz band at a specified offset from the fundamental frequency to the power value of the fundamental. This ratio is expressed in decibels (dBm) or a ratio of the power in the 1Hz band

to the power in the fundamental. When the required offset is specified, the phase noise is called a *dBc* value, which simply means dBm at a specified offset from the fundamental. By investigating jitter in the frequency domain, we get a better understanding of its effects on the desired application over the entire time record of the signal. It is mathematically possible to calculate an expected bit error rate given a phase noise plot.

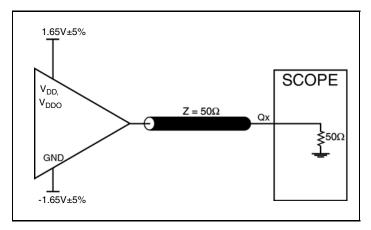


As with most timing specifications, phase noise measurements has issues relating to the limitations of the equipment. Often the noise floor of the equipment is higher than the noise floor of the

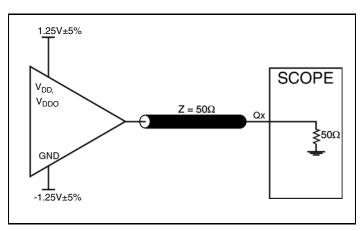
device. This is illustrated above. The device meets the noise floor of what is shown, but can actually be lower. The phase noise is dependent on the input source and measurement equipment.



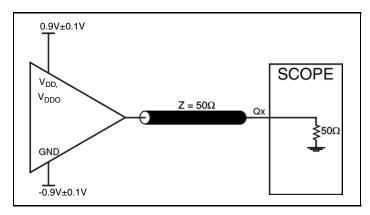
Parameter Measurement Information



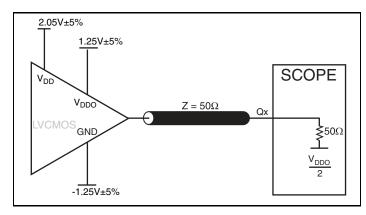
3.3V Core/3.3V LVCMOS Output Load AC Test Circuit



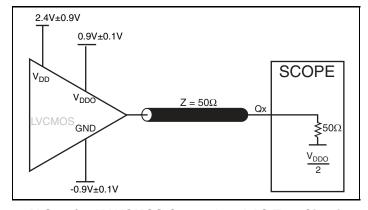
2.5V Core/2.5V LVCMOS Output Load AC Test Circuit



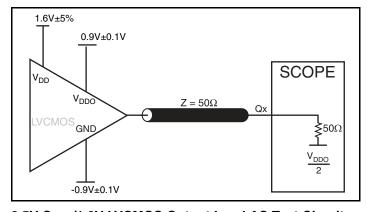
1.8V Core/1.8V LVCMOS Output Load AC Test Circuit



3.3V Core/2.5V LVCMOS Output Load AC Test Circuit



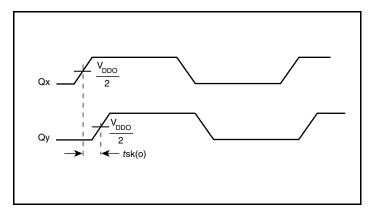
3.3V Core/1.8V LVCMOS Output Load AC Test Circuit



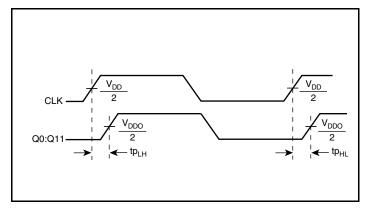
2.5V Core/1.8V LVCMOS Output Load AC Test Circuit



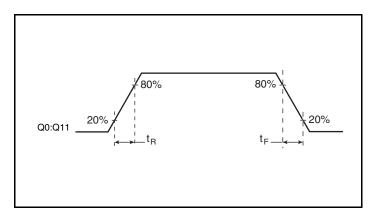
Parameter Measurement Information, continued



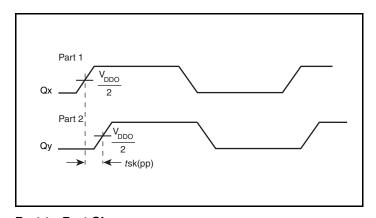
Output Skew



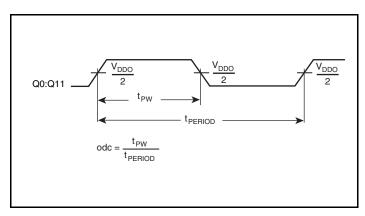
Propagation Delay



Output Rise/Fall Time



Part-to-Part Skew



Output Duty Cycle/Pulse Width/Period



Application Information

Recommendations for Unused Input and Output Pins

Inputs:

LVCMOS Control Pins:

All control pins have internal pull-ups or pull-downs; additional resistance is not required but can be added for additional protection. A 1k Ω resistor can be used.

Outputs:

LVCMOS Outputs:

All unused LVCMOS output can be left floating. There should be no trace attached.



Reliability Information

Table 6. θ_{JA} vs. Air Flow Table for a 32 Lead LQFP

$ heta_{JA}$ vs. Air Flow				
Linear Feet per Minute	0	200	500	
Single-Layer PCB, JEDEC Standard Test Boards	67.8°C/W	55.9°C/W	50.1°C/W	
Multi-Layer PCB, JEDEC Standard Test Boards	47.9°C/W	42.1°C/W	39.4°C/W	

NOTE: Most modern PCB design use multi-layered boards. The data in the second row pertains to most designs.

Transistor Count

The transistor count for 8312l is: 339



Package Outline and Package Dimensions

Package Outline - Y Suffix for 32 Lead LQFP

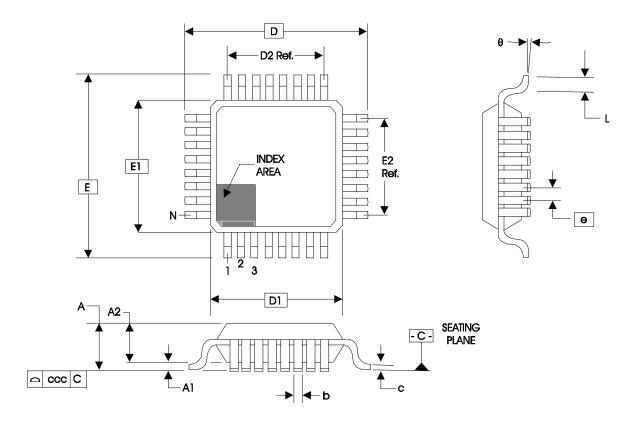


Table 7. Package Dimensions for 32 Lead LQFP

JEDEC Variation: ABC - HD All Dimensions in Millimeters						
Symbol	Minimum	Nominal	Maximum			
N		32				
Α			1.60			
A1	0.05	0.10	0.15			
A2	1.35	1.40	1.45			
b	0.30	0.37	0.45			
С	0.09		0.20			
D&E		9.00 Basic				
D1 & E1		7.00 Basic				
D2 & E2		5.60 Ref.				
е		0.80 Basic				
L	0.45	0.60	0.75			
θ	0°		7°			
ccc			0.10			
N		32				

Reference Document: JEDEC Publication 95, MS-026



Ordering Information

Table 8. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
8312AYILF	ICS8312AYILF	"Lead-Free" 32 Lead LQFP	Tray	-40°C to 85°C
8312AYILFT	ICS8312AYILF	"Lead-Free" 32 Lead LQFP	1000 Tape & Reel	-40°C to 85°C



Revision History Sheet

Rev	Table	Page	Description of Change	Date
Α	Т8	1 9 12	Features section - added lead-free bullet. Added Recommendations for Unused Input & Output Pins section. Ordering Information Table - added Lead-Free part number, marking and note.	6/28/06
В	T5A - T5F	7 - 9 10	Added Additive Phase Jitter specs to AC Tables. Added Additive Phase Jitter Plot. Updated datasheet to new format.	6/6/08
В	8	1 16	Updated Datasheet format Ordering Information - removed leaded devices - PDN CQ-13-02 expired.	11/4/14
В		1 16	Removed HiPerClockS from the description section. Removed LF note below the Ordering information table. Updated datasheet header and footer.	12/14/15



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